

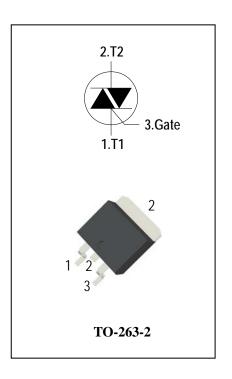
3 Quadrants High temperature Triacs

General Description

High current density due to mesa technology , guaranteed maximum junction temperature 150° C. The ADS20CH triac series is suitable for general purpose AC switching. They can beused as an ON/OFF function in applications such as static relays, heating regulation, High power motor controls e.g. washing machines and vacuum cleaners,Rectifier-fed DC inductive loads e.g.DC motors and solenoids , motor speed controllers. The heatsink can be reduced,compared to traditional triacs, according to the high performance at given junction temperatures.

Features

- ◆ Repetitive Peak Off-State Voltage: 600V/800V
- ◆ R.M.S On-State Current (IT(RMS)= 20A)
- ♦ High Commutation dv/dt
- ◆ High junction temperature operating capability
- ◆ These Devices are Pb-Free and are RoHS Compliant



Absolute Maximum Ratings

| Symbol | Items | Conditions | | Ratings | Unit |
|---------------------|--|-------------------------------|------------|------------|------------------|
| V_{DRM} | Denetitive Deals Off Ctate Valtage | T: - 25°C | ADS20CH60G | 600 | V |
| V_{RRM} | Repetitive Peak Off-State Voltage | Tj = 25°C | ADS20CH80G | 800 | V |
| I _{T(RMS)} | R.M.S On-State Current | T _C = 129 °C | | 20 | Α |
| I _{TSM} | Surge On-State Current | tp=20ms(50Hz)/tp=16.7ms(60Hz) | | 200/210 | Α |
| l ² t | I ² t for fusing | tp=10ms | | 265 | A ² s |
| -11/-14 | Critical rate of rise of on-state | F = 120 Hz Tj = 150°C | | 50 | A / |
| dl/dt | current $I_G = 2 \times I_{GT}$, tr $\leq 100 \text{ ns}$ | | 50 | A/µs | |
| I _{GM} | Peak Gate Current | tp = 20 μs Tj = 150°C | | 4 | Α |
| $P_{G(AV)}$ | Average Gate Power Dissipation(Tj=150°C) | | | 1 | W |
| P_{GM} | Peak Gate Power Dissipation(tp=20us,Tj=150°C) | | | 10 | W |
| Tj | Operating Junction Temperature | | | - 40 ~ 150 | °C |
| T _{STG} | Storage Temperature | | | - 40 ~ 150 | °C |





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Electrical Characteristics(Tj = 25°C unless otherwise specified)

| Symbol | Items C | | Conditions | | ADS20CH60G/80 | | /80G | Unit |
|----------------------|--|-----------------------------|---|----------------------------|---------------|-------|------|------|
| | | | | | S | Blank | В | |
| I _{DRM} | Peak Forward Reverse Blocking | | $V_{DRM} = V_{RRM}$, $Tj = 25$ °C | May | 5 | | uA | |
| I _{RRM} | Current | | $V_{DRM} = V_{RRM}$, $Tj = 150$ °C | Max. | 6.2 | | mA | |
| V _{TM} | Peak On-S | tate Voltage | I _{TM} = 28A, t _p = 380 μs | Max. | 1.5 | | | V |
| V_{GD} | Q1-Q2-Q3 | Non-Trigger Gate Voltage | $V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 150^{\circ}\text{C}$ | Min. | 0.15 | | > | |
| V_{GT} | Q1-Q2-Q3 | Gate Trigger Voltage | V 40V D 200 | Max. | 1.3 | | | V |
| I _{GT} | Q1-Q2-Q3 | Gate Trigger Current | $V_D = 12V$, $R_L = 33\Omega$ | Max. | 10 | 35 | 50 | mA |
| I _H | Q1-Q2-Q3 | Holding Current | I _T = 0.1A | Max. | 20 | 50 | 75 | mA |
| IL | Q1-Q3 | Latabia a Commant | 1 - 401 | = 1.2 I _{GT} Max. | 20 | 80 | 90 | mA |
| | Q2 | Latching Current | I _G = 1.2 I _{GT} | | 35 | 90 | 110 | |
| dV/dt | Critical Rate of Rise of Off-State Voltage | | $V_D = 2/3V_{DRM}$ gate open Tj = 150°C | Min. | 500 | 1000 | 1500 | V/µs |
| (dV/dt)c | Critical Rate of Change of Commutating Voltage | | V_D =400V Tj = 150°C (dl/dt)c=-8.8A/ms | Min. | 1 | 15 | 20 | V/µs |
| R _{th(j-c)} | Junction to case (AC) | | Max. | 1 | | °C/W | | |
| R _{th(j-a)} | Junction to ambient(Copper surface under tab:S=1cm²) | | Max. | 45 | | | °C/W | |

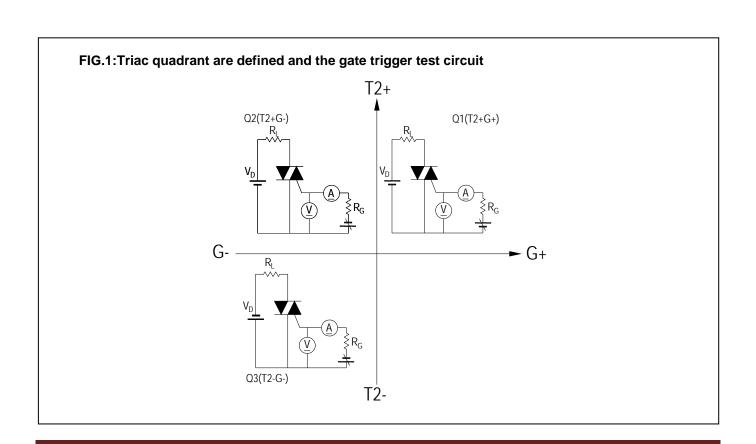




FIG.2: Maximum on-state power dissipation

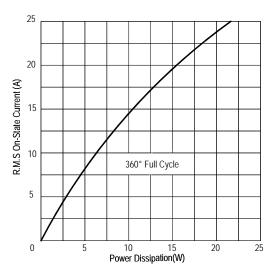


FIG.4: Maximum transient thermal impedance

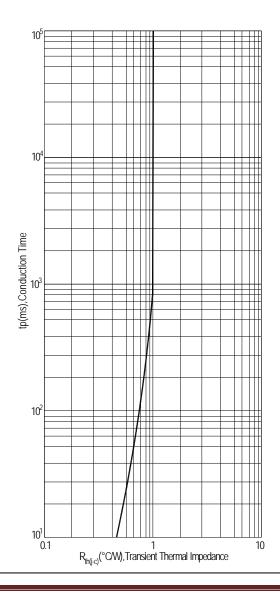


FIG.3: Typical RMS on-state current VS Allowable case Temperature

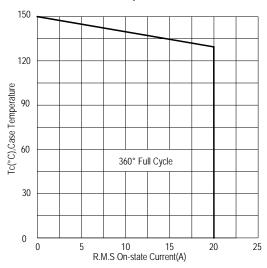


FIG.5: Rated surge on-state current (Non-Repetitive)

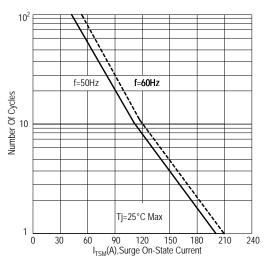
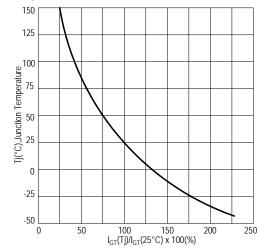


FIG.6: Gate trigger current VS Junction temperature





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FIG.7:Holding current and Latching current VS Junction temperature

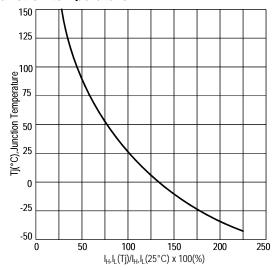


FIG.8: Gate trigger voltage VS Junction temperature

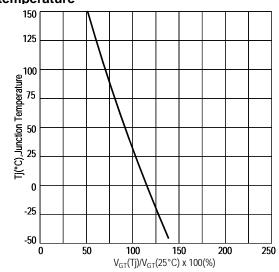
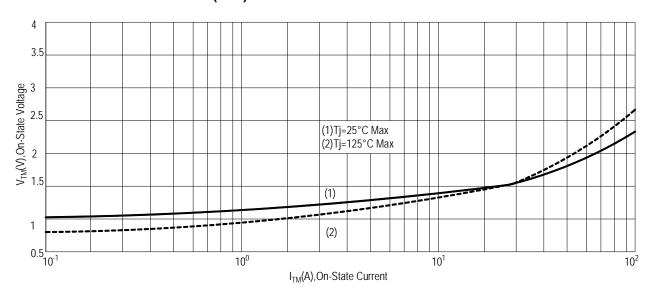


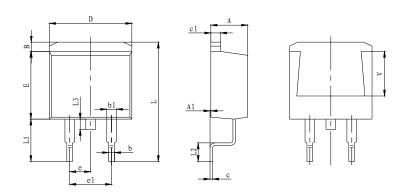
FIG.9: On-state characteristics(Max)



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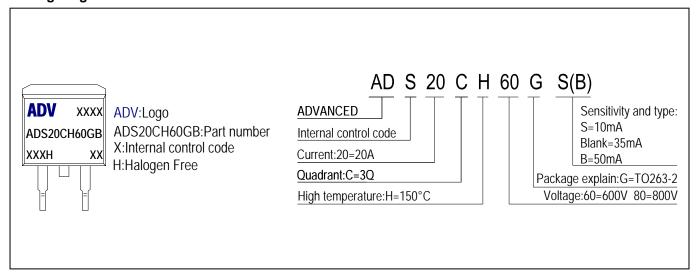


PACKAGE MECHANICAL DATA TO-263-2 Package Dimension



| Symb | Dimer | nsions | Dimensions | | |
|------|----------------|--------|------------|-------|--|
| Symb | In Millimeters | | In Inches | | |
| 01 | Min | Max | Min | Max | |
| А | 4.470 | 4.670 | 0.176 | 0.184 | |
| A1 | 0.000 | 0.150 | 0.000 | 0.006 | |
| В | 1.170 | 1.370 | 0.046 | 0.054 | |
| b | 0.710 | 0.910 | 0.028 | 0.036 | |
| b1 | 1.170 | 1.370 | 0.046 | 0.054 | |
| С | 0.310 | 0.530 | 0.012 | 0.021 | |
| c1 | 1.170 | 1.370 | 0.046 | 0.054 | |
| D | 10.010 | 10.310 | 0.394 | 0.406 | |
| E | 8.500 | 8.900 | 0.335 | 0.350 | |
| е | 2.540 TYP | | 0.100 TYP | | |
| e1 | 4.980 | 5.180 | 0.196 | 0.204 | |
| L | 15.050 | 15.450 | 0.593 | 0.608 | |
| L1 | 5.080 | 5.480 | 0.200 | 0.216 | |
| L2 | 2.340 | 2.740 | 0.092 | 0.108 | |
| L3 | 1.300 | 1.700 | 0.051 | 0.067 | |
| V | 5.600 REF | | 0.220 REF | | |

Making Diagram



Ordering information

| Part number | Package | Marking | Packing | Quantity | | |
|--|----------|-------------|---------------|----------|--|--|
| ADS20CH60G# | TO-263-2 | ADS20CH60G# | Tube | 50pcs | | |
| ADS20CH00G# | | | Embossed tape | 800pcs | | |
| ADS20CH80G# | TO-263-2 | ADS20CH80G# | Tube | 50pcs | | |
| ADS20CH60G# | | | Embossed tape | 800pcs | | |
| Note:# = Gate Trigger Current Sensitivity and type | | | | | | |



ADS20CH60G/80G

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